

TVS Diodes

Transient Voltage Suppressor Diodes

ESD8V0R1B Series

Bi-directional Low Capacitance TVS Diode

ESD8V0R1B-02EL
ESD8V0R1B-02ELS

Data Sheet

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Revision History

Page or Item	Subjects (major changes since previous revision)
Revision 1.0, 2010-10-20	
Revision 2.0, 2010-12-15	
	Carrier Tape drawing for TSSLP-2-2 Package updated

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Last Trademarks Update 2010-06-09

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1 Bi-directional Low Capacitance TVS Diode

1.1 Features

- ESD / Transient protection of data lines in 3.3 / 5 / 12 V applications according to :
 - IEC61000-4-2 (ESD) : ± 20 kV (air) and ± 18 kV (contact)
 - IEC61000-4-4 (EFT) : 40 A (5/50ns)
- Extremely small form factor down to $0.62 \times 0.32 \times 0.31$ mm²
- Maximum working voltage: $V_{RWM} = -8 / +14$ V
- Very low reverse current: $I_R < 1$ nA (typical)
- Very low series inductance down to : $L_S = 0.2$ nH (typical)
- Low capacitance $C_L = 4$ pF I/O to GND (typical)
- Pb-free and Halogen-Free package (RoHS compliant)

1.2 Application Examples

- Keypad, touchpad, buttons, convenience keys
- LCD displays, Camera, audio lines, mobile communication, Consumer products (E-Book, MP3, DVD, DSC, ...)
- Notebooks tablets and desktop computers and their peripherals



2 Product Description

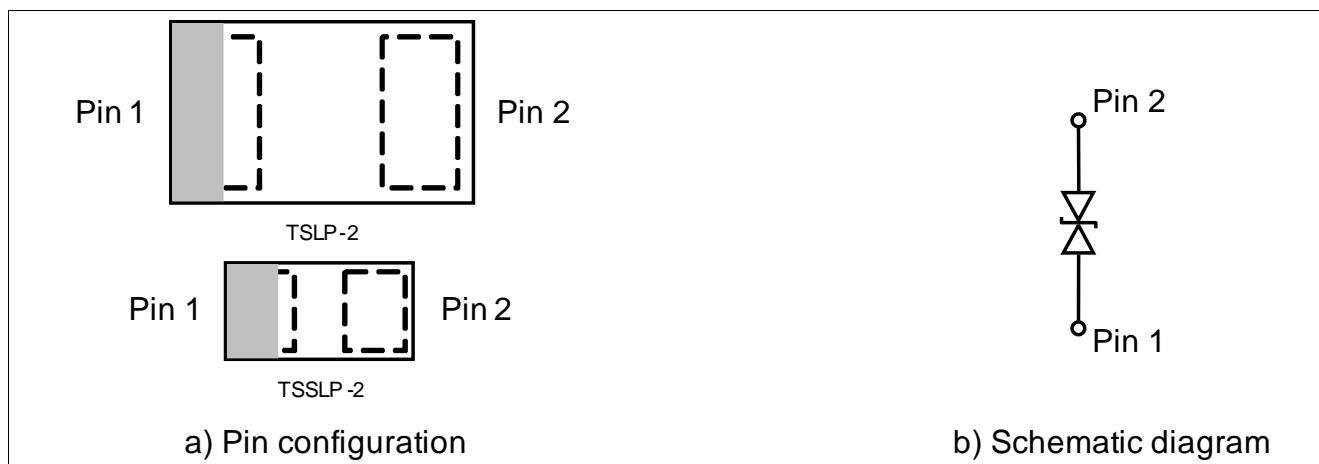


Figure 1 a) Pin Configuration and b) Schematic Diagram

Table 1 Ordering information

Type	Package	Configuration	Marking code
ESD8V0R1B-02EL	PG-TSLP-2-18	1 line, bi-directional	R
ESD8V0R1B-02ELS	PG-TSSLP-2-2	1 line, bi-directional	D

3 Characteristics

Table 2 Maximum Rating at $T_A = 25\text{ }^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
ESD air discharge ¹⁾	V_{ESD}	-20	–	20	kV
ESD contact discharge ¹⁾	V_{ESD}	-18	–	18	kV
Peak pulse current ($t_p = 8/20\ \mu\text{s}$) ²⁾	I_{PP}	-1	–	1	A
Operating temperature	T_{OP}	-55	–	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-65	–	150	$^\circ\text{C}$

1) V_{ESD} according to IEC61000-4-2

2) I_{PP} according to IEC61000-4-5

3.1 Electrical Characteristics at $T_A = 25\text{ }^\circ\text{C}$, unless otherwise specified

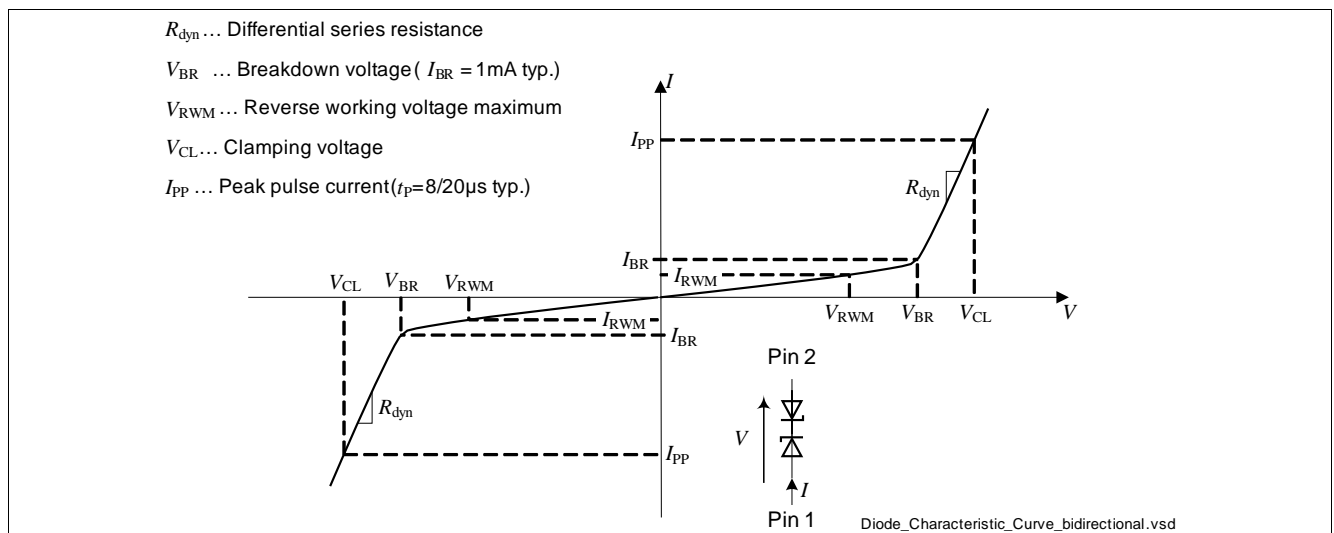


Figure 2 Definitions of electrical characteristics

Table 3 DC characteristics at $T_A = 25\text{ }^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Reverse working voltage	V_{RWM}	-8	–	14	V	from Pin2 to Pin1
Breakdown voltage	V_{BR}	8.5	11	14	V	$I_R = 1\text{ mA}$, from Pin1 to Pin2
Breakdown voltage	V_{BR}	14.5	17	20	V	$I_R = 1\text{ mA}$, from Pin2 to Pin1
Reverse current	I_R	–	<1	50	nA	$V_R = 3.3\text{ V}$

Table 4 RF characteristics at $T_A = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Line capacitance	C_L	–	4	7	pF	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$, I/O to GND
Serie inductance	L_S	–	0.4	–	nH	ESD8V0R1B-02EL
	L_S	–	0.2	–	nH	ESD8V0R1B-02ELS

Table 5 ESD characteristics at $T_A = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Clamping voltage ¹⁾	V_{CL}	–	17	22	V	$I_{PP} = 1\text{ A}$ from Pin1 to Pin2
	V_{CL}	–	23	28	V	$I_{PP} = 1\text{ A}$ from Pin2 to Pin1

1) According to IEC61000-4-5 ($t_p : 8 / 20\text{ }\mu\text{s}$)

3.2 Typical Performance characteristics at $T_A = 25\text{ }^\circ\text{C}$, unless otherwise specified

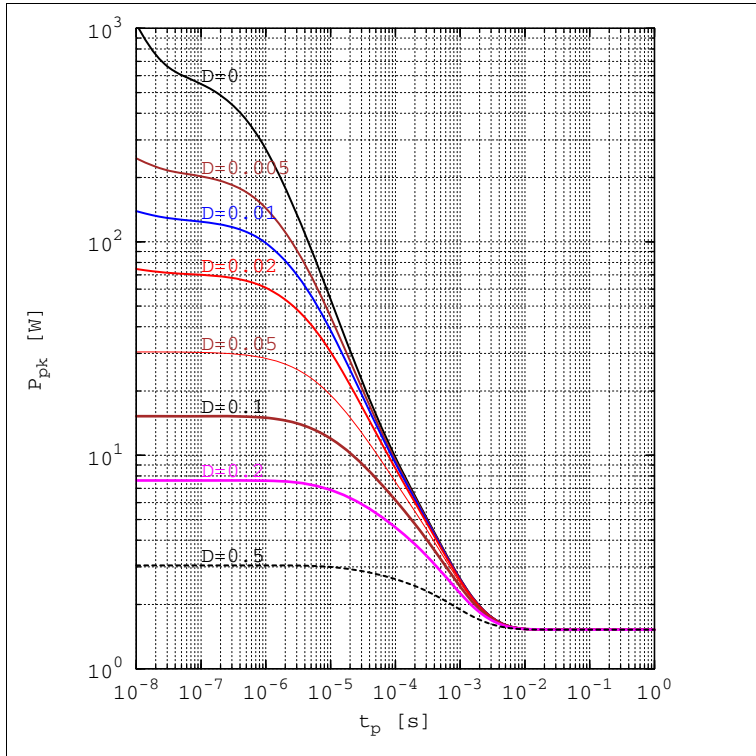


Figure 3 Non-repetitive peak pulse power: $P_{pk} = f(t_p)$

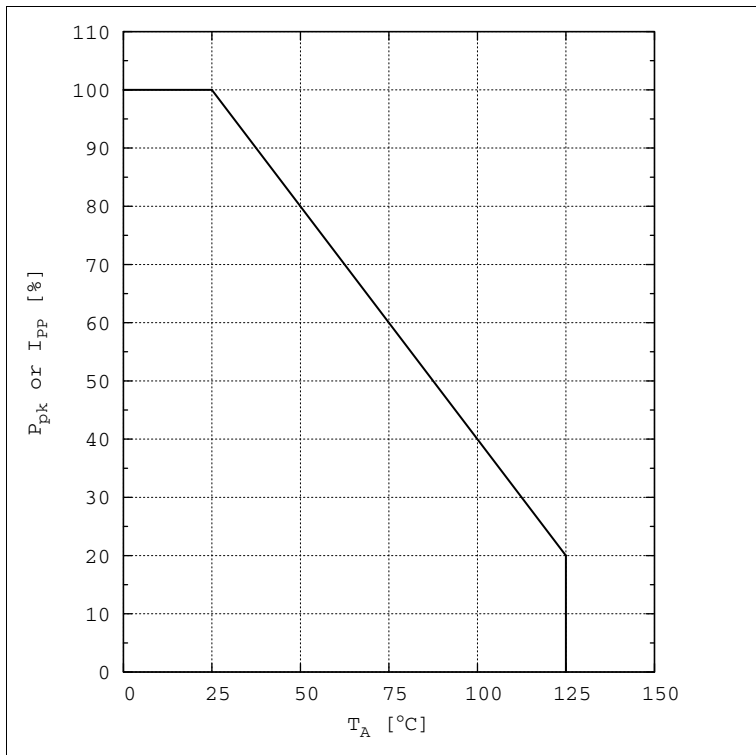


Figure 4 Power derating curve: $P_{pk} = f(T_A)$

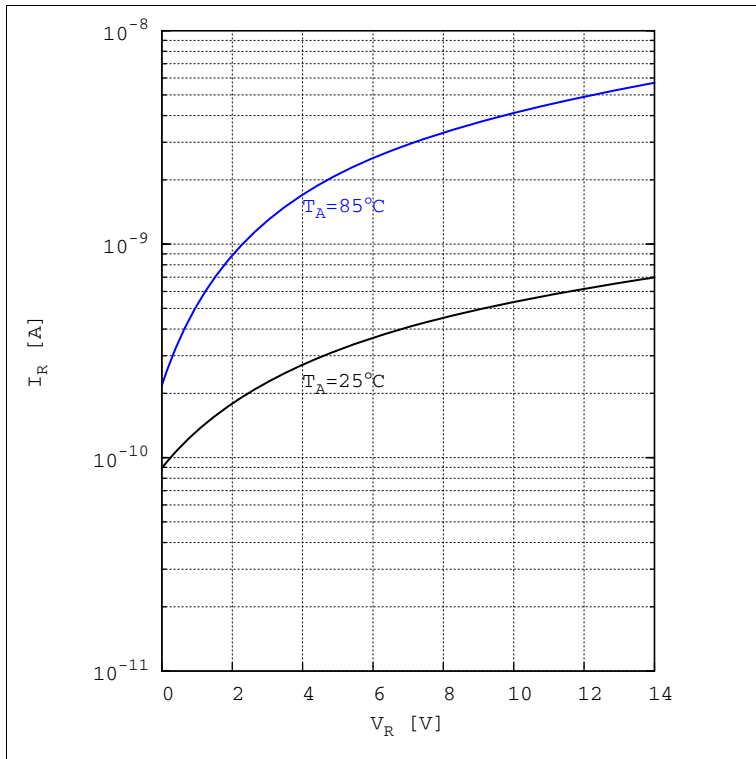


Figure 5 Reverse characteristic, $I_R = (V_R)$, $T_A =$ parameter

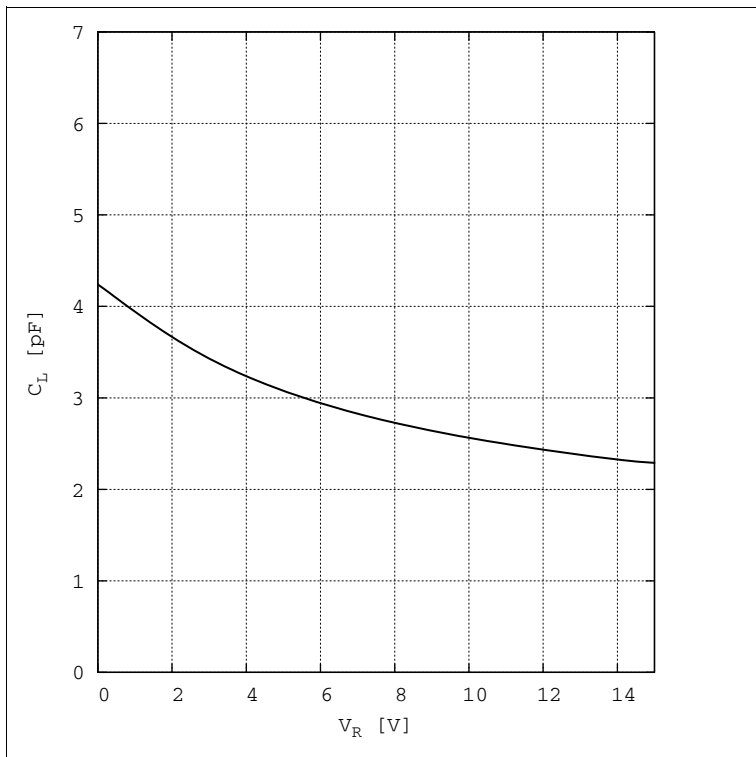


Figure 6 Line capacitance $C_L = f(V_R)$

4 Application Information

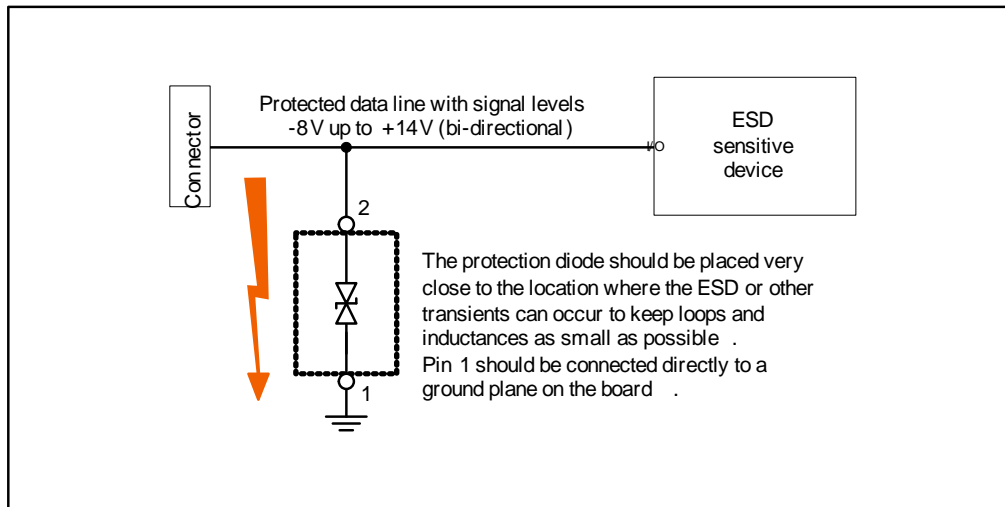


Figure 7 1 Line, bi-directional protection with ESD diode

5 Ordering information scheme

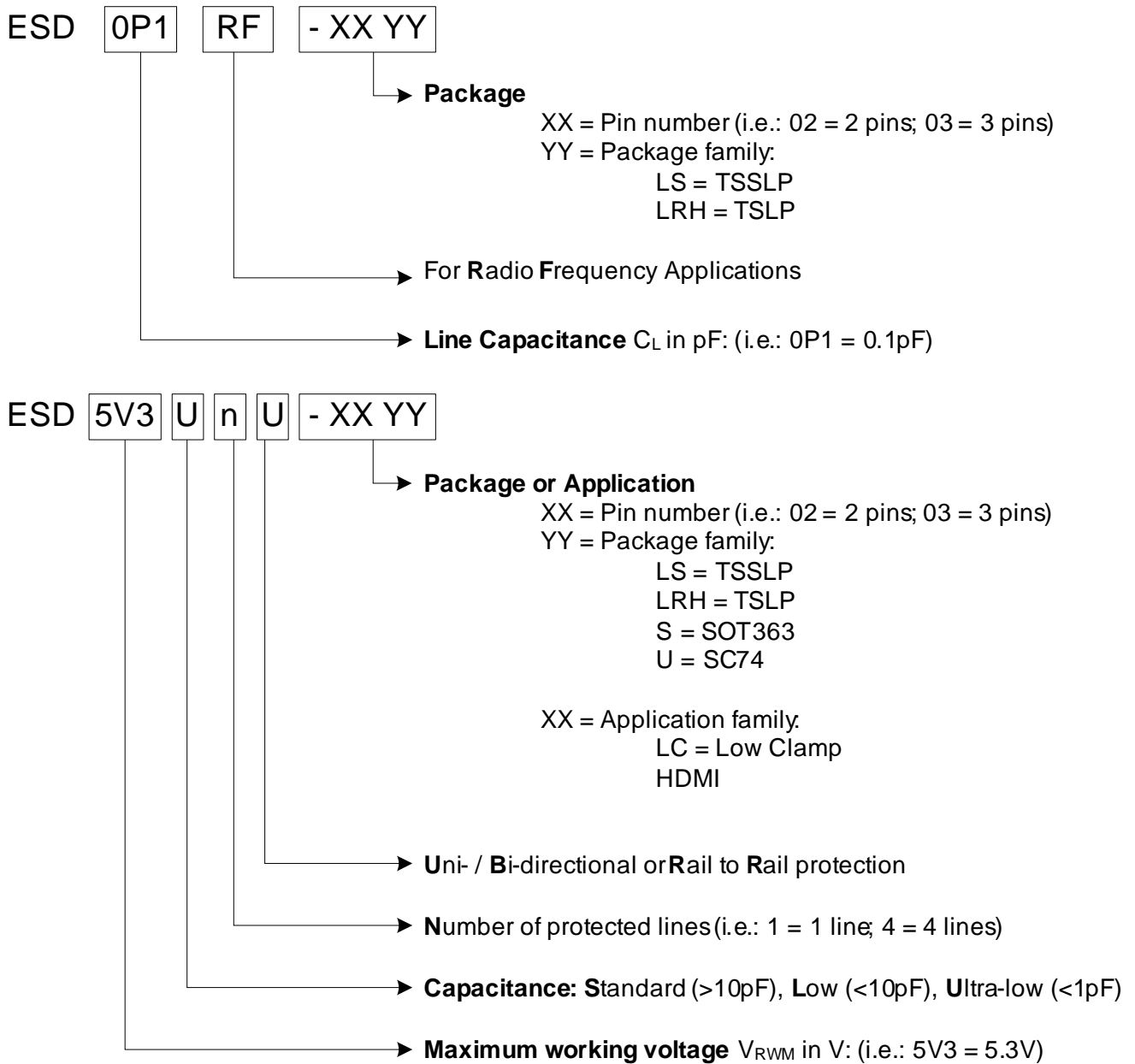
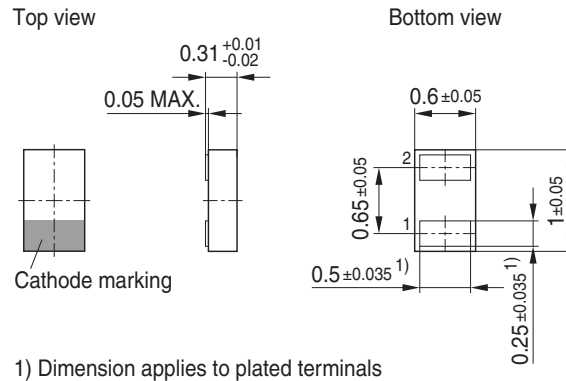


Figure 8 Ordering Information Scheme (examples)

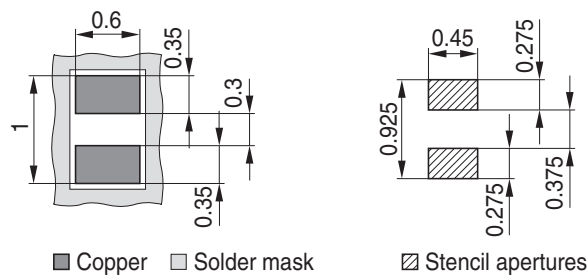
6 Package Information

6.1 PG-TSLP-2-18



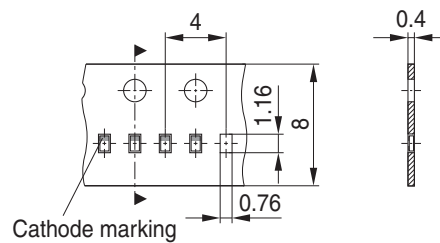
TSLP-2-18-PO V01

Figure 9 PG-TSLP-2-18: Package Overview



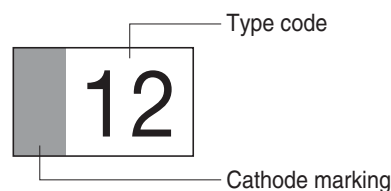
TSLP-2-18-FP V01

Figure 10 PG-TSLP-2-18: Footprint



TSLP-2-18-TP V01

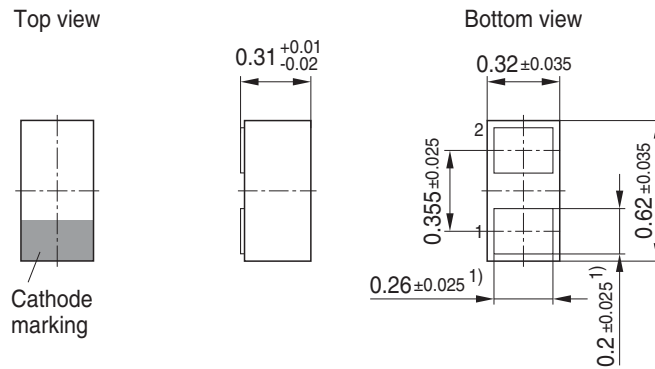
Figure 11 PG-TSLP-2-18: Packing



TSLP-2-18-MK V01

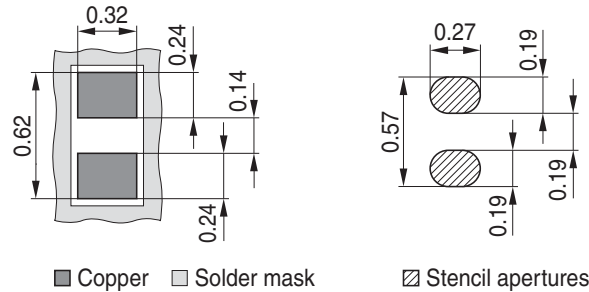
Figure 12 PG-TSLP-2-18: Marking (example)

6.2 PG-TSSLP-2-2



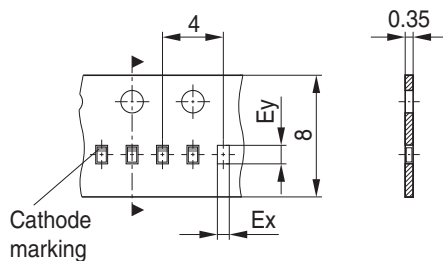
TSSLP-2-1,-2-PO V05

Figure 13 PG-TSSLP-2-2: Package Overview



TSSLP-2-1,-2-FP V02

Figure 14 PG-TSSLP-2-2: Footprint



Tape type	Ex	Ey
Punched Tape	0.43	0.73
Embossed Tape	0.37	0.67

Deliveries can be both tape types (no selection possible).
Specification allows identical processing (pick & place) by users.

TSSLP-2-1,-2-TP V03

Figure 15 PG-TSSLP-2-2: Packing

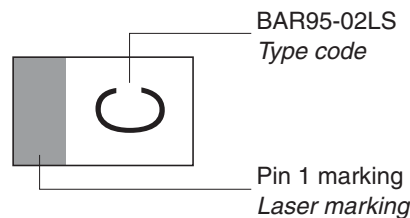


Figure 16 PG-TSSLP-2-2: Marking (example)

Terminology

C_L	Line capacitance
DSC	Digital Still Camera
DVD	Digital Versatile Disc
EFT	Electrical Fast Transient
ESD	Electrostatic Discharge
IEC	International Electrotechnical Commission
I_{PP}	Peak pulse current
I_R	Reverse current
I_{RWM}	Reverse working current maximum
LCD	Liquid Crystal Display
L_S	Serial inductance
MP3	Moving Picture Experts Group III
RoHS	Restriction of Hazardous Substances Directive
T_A	Ambient temperature
T_{OP}	Operation temperature
t_p	Pulse duration
T_{stg}	Storage temperature
V_{CL}	Reverse clamping voltage
V_{ESD}	Electrostatic discharge voltage
V_R	Reverse voltage
V_{RWM}	Reverse working voltage maximum

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